

Product Status Information

HL8337MG-A is Not Recommended for New Design (NRND) status. Please refer to successor product below for new design and adoption.

NRND Product	Successor Product		
HL8337MG-A	HL85022MG		
https://www.ushio.co.jp/jp/products/product_file/file/UIE_DS_HL8337MG.pdf	https://www.ushio.co.jp/jp/products/product_file/file/UIE_DS_HL85022MG.pdf		

For the "Product Life Cycle" definition, please refer to below link. Japanese; <u>https://www.ushio.co.jp/jp/laser/news/500958.html</u> English; <u>https://www.ushio.co.jp/en/laser/news/500958.html</u>

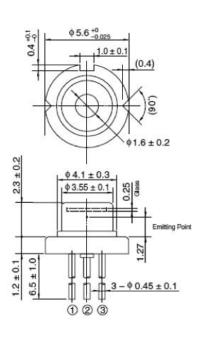


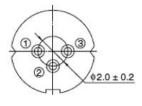
HL8337MG-A/38MG-A

830nm/50mW Ga

GaAlAs Laser Diode

Outline



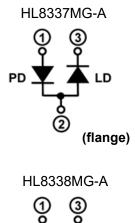


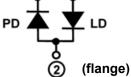
(Unit:mm)

Features

- Operation temperature: -10~+60°C
- Optical output power: 50mW(CW)
- Infrared lasing: 830nm Typ.
- Low operating voltage: 2.4V Max.
- Single transverse mode
- TE mode oscillation

Internal Circuit





Application

- Sensor application
- Night vision
- Machine vision
- Light source of optical equipments

HL8337MG/38MG-A

Data Sheet

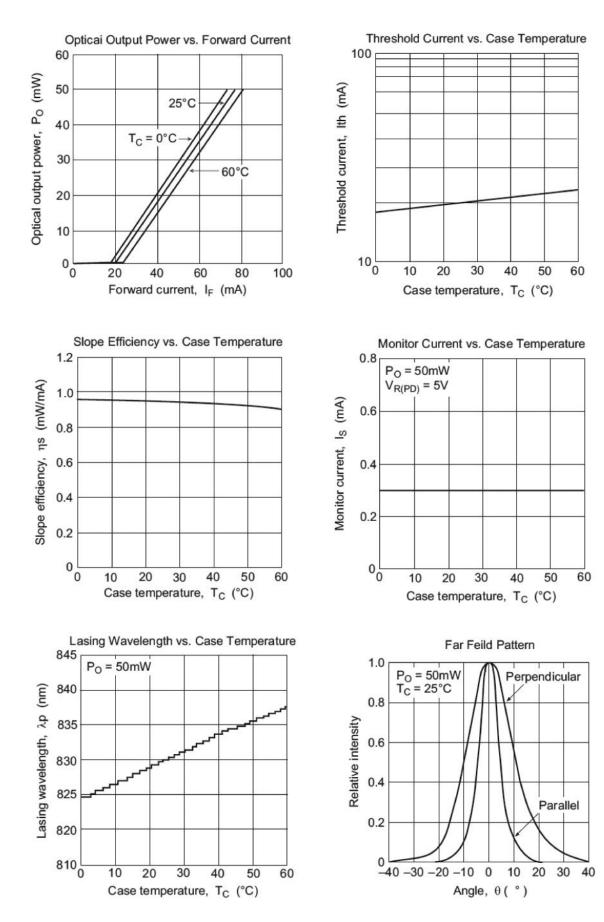
Absolute Maximum Ratings (Tc=25°C)

ltem	Symbol	Ratings	Unit
Optical output power	Ро	50	mW
LD Reverse Voltage	VR(LD)	2	V
PD Reverse Voltage	Vr(pd)	30	V
Operating Temperature	Topr	-10 ~ +60	°C
Storage Temperature	Tstg	-40 ~ +85	°C

Optical and Electrical Characteristics (Tc=25°C)

Parameter	Symbol	Min	Тур	Мах	Unit	Test Condition
Threshold current	lth	-	20	40	mA	-
Operating current	Іор	-	75	100	mA	Po=50mW
Operating voltage	Vop	-	1.9	2.4	V	Po=50mW
Beam divergence Parallel to the junction	θ//	6	9	12	o	Po=50mW, FWHM
Beam divergence Perpendicular to the junction	θ⊥	18	22	26	o	Po=50mW, FWHM
Lasing Wavelength	λρ	820	830	840	nm	Po=50mW
Monitor Current	ls	0.10	0.25	0.50	mA	Po=50mW, V _{R(PD)} =5V

Typical Characteristic Curves



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1. The laser light is harmful to human body especially to eye no matter what directly or indirectly. The laser beam shall be observed or adjusted through infrared camera or equivalent.

2. This product (without violet laser diode) contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product. When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.

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